NSN 5962-01-219-6695

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Body	Length:
-	inches
	Width:
	een 0.220 inches and 0.310 inches
	r Height:
	inches
	mum Power Dissipation Rating:
	milliwatts
	ating Tempurature Range:
	/+125.0 degrees celsius
	ge Tempurature Range:
	/+150.0 degrees celsius
	ires Provided:
Herm	etically sealed and burn in and w/active pull-up and programmed and w/enable
	sure Material:
Cerar	nic
Inclo	sure Configuration:
	in-line
Outp	ut Logic Form:
	- sistor-transistor logic
	Circuit Pattern:
10 inp	
Case	Outline Source And Designator:
	- nil-m-38510
Term	inal Surface Treatment:
Solde	r
Volta	ge Rating And Type Per Characteristic:
-0.5 v	olts power source and 7.0 volts power source
Time	Rating Per Chacteristic:
85.00	nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
outpu	t
Mem	ory Device Type:
Rom	
Mem	ory Capacity:
Unkn	own
Test	Data Document:
9690(6-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Term	inal Type And Quantity:
16 pr	inted circuit
Shelf	Life:
N/a	
Unit	Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

